DU2880T



RF Power MOSFET Transistor 80W, 2-175MHz, 28V

M/A-COM Products Released; RoHS Compliant

Features

- N- channel enhancement mode device
- DMOS structure
- Lower capacitances for broadband operation
- · High saturated output power
- Lower noise figure than bipolar devices

ABSOLUTE MAXIMUM RATINGS AT 25° C

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	65	V
Gate-Source Voltage	V _{GS}	20	V
Drain-Source Current	I _{DS}	16	Α
Power Dissipation	P_D	206	W
Junction Temperature	TJ	200	°C
Storage Temperature	T _{STG}	-65 to +150	°C
Thermal Resistance	θ_{JC}	0.85	°C/W

TYPICAL DEVICE IMPEDANCE

F (MHz)	$Z_{IN}(\Omega)$ $Z_{LOAD}(\Omega)$				
30	5.4 - j4.4 5.7 +j4.7				
50	2.5 - j4.4	3.4 + j3.5			
100	1.6 - j3.4	2.4 + j2.4			
175	0.7 - j1.2 1.7 + j0.8				
V _{DD} = 28V, I _{DQ} = 400mA, P _{OUT} = 80 W					

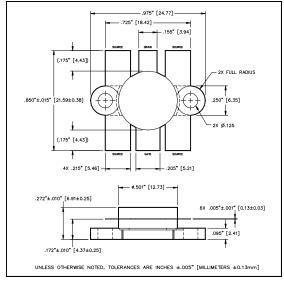
 $Z_{\mbox{\scriptsize IN}}$ is the series equivalent input impedance of the device from gate to source.

 Z_{LOAD} is the optimum series equivalent load impedance as measured from drain to ground.

ELECTRICAL CHARACTERISTICS AT 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions		
Drain-Source Breakdown Voltage	BV _{DSS}	65	-	V	V _{GS} = 0.0 V , I _{DS} = 20.0 mA		
Drain-Source Leakage Current	I _{DSS}	-	4.0	mA	V _{GS} = 28.0 V , V _{GS} = 0.0 V		
Gate-Source Leakage Current	I _{GSS}	-	4.0	μA	V _{GS} = 20.0 V , V _{DS} = 0.0 V		
Gate Threshold Voltage	$V_{GS(TH)}$	2.0	6.0	V	V _{DS} = 10.0 V , I _{DS} = 400.0 mA		
Forward Transconductance	G _M	2.0	-	S	V_{DS} = 10.0 V , I_{DS} = 4.0 A , Δ V_{GS} = 1.0V, 80 μ s Pulse		
Input Capacitance	C _{ISS}	-	180	pF	V _{DS} = 28.0 V , F = 1.0 MHz		
Output Capacitance	Coss	-	160	pF	V _{DS} = 28.0 V , F = 1.0 MHz		
Reverse Capacitance	C _{RSS}	-	32	pF	V _{DS} = 28.0 V , F = 1.0 MHz		
Power Gain	G _P	13	-	dB	V _{DD} = 28.0 V, I _{DQ} = 400 mA, P _{OUT} = 60.0 W F =175 MHz		
Drain Efficiency	η _D	60	-	%	V_{DD} = 28.0 V, I_{DQ} = 400 mA, P_{OUT} = 60.0 W F =175 MHz		
Load Mismatch Tolerance	VSWR-T	-	30:1	-	V_{DD} = 28.0 V, I_{DQ} = 400 mA, P_{OUT} = 60.0 W F =175 MHz		

Package Outline



LETTER	MILLIM	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	24.38	25.15	.960	990
В	18.29	18.54	.720	.730
С	21.36	21.74	.841	.856
D	12.60	12.85	.496	.506
E	5.33	5.59	.210	.220
F	5.08	5.33	.200	.210
G	3.81	4.06	.150	.160
Н	3.10	3.15	.122	.128
J	2.51	2.67	.099	.105
К	4.06	4.57	.160	.180
L	6.68	7.49	.263	.295
М	.10	.15	.004	.005

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

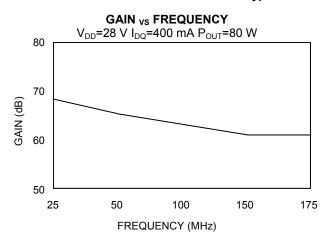
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

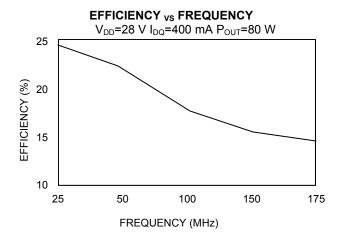


RF Power MOSFET Transistor 80W, 2-175MHz, 28V

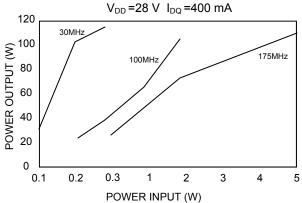
M/A-COM Products Released; RoHS Compliant

Typical Broadband Performance Curves





POWER OUTPUT _{VS} POWER INPUT



120 (M) 100 (M) 40 (M) 40

20

SUPPLY VOLTAGE (W)

25

30

33

POWER OUTPUT _{VS} SUPPLY VOLTAGE

13

15

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

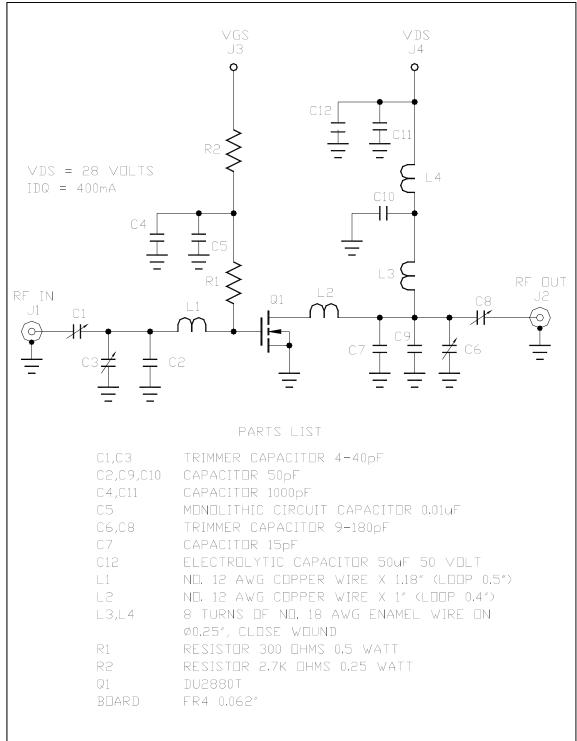
Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



RF Power MOSFET Transistor 80W, 2-175MHz, 28V

M/A-COM Products Released; RoHS Compliant

TEST FIXTURE SCHEMATIC



PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.